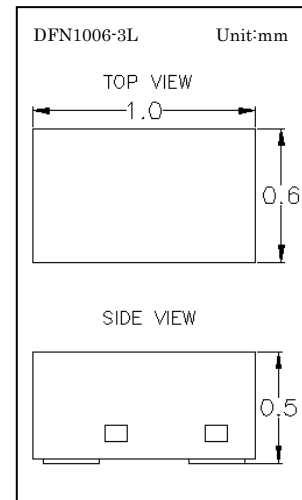


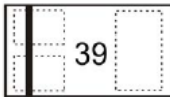
### Features

- P-Channel Switch with Low  $R_{DS(on)}$
- Surface Mount Package
- ROHS Compliant & Halogen-Free
- ESD Protection

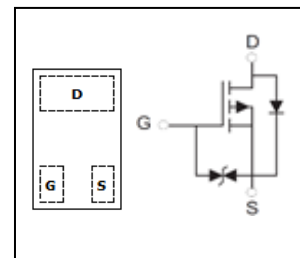
### Package



### Device Marking Code



### Circuit Diagram



### Maximum Ratings (Ta=25°C Unless Otherwise Noted)

Symbol	Parameter	Value	Unit
$V_{DS}$	Drain-Source Voltage	-20	V
$V_{GS}$	Gate-Source Voltage	±8	V
$I_D$	Drain Current-Continuous*1	-0.66	A
$I_{DM}$	Pulsed Drain Current	-2.1	A
$P_D$	Power Dissipation*1	0.15	W
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient*1	833	°C/W
$T_j$	Junction Temperature	150	°C
$T_{stg}$	Storage Temperature	-55~+150	°C



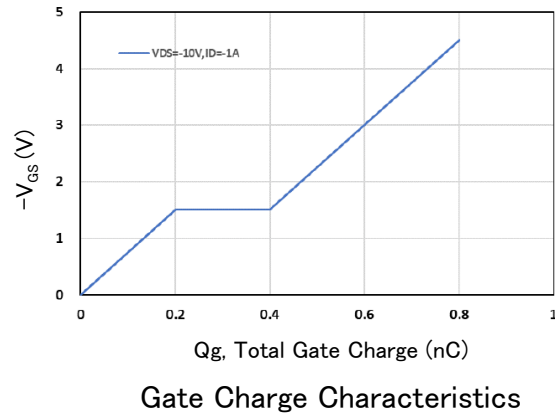
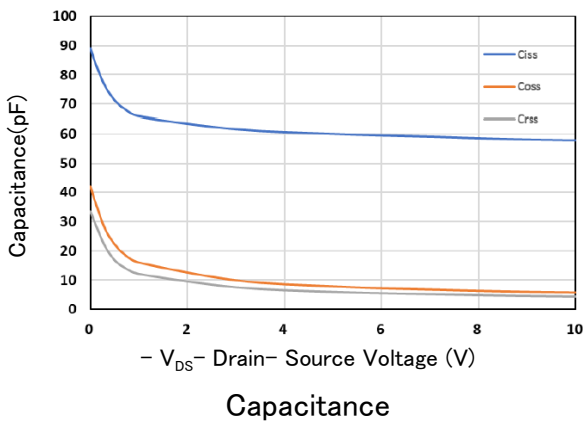
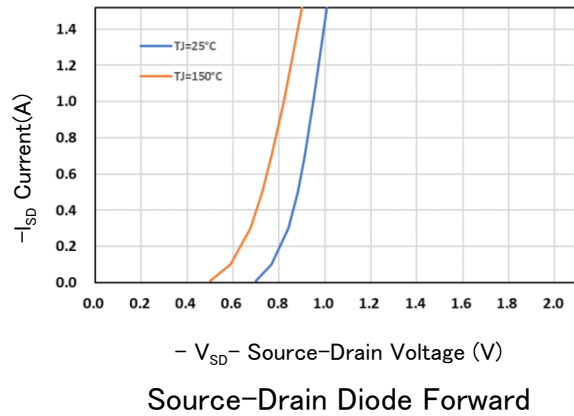
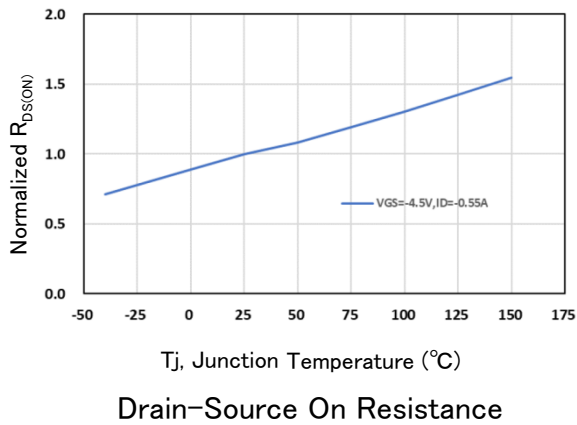
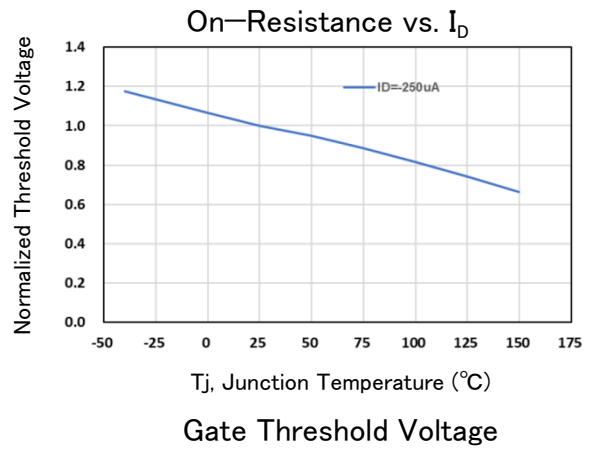
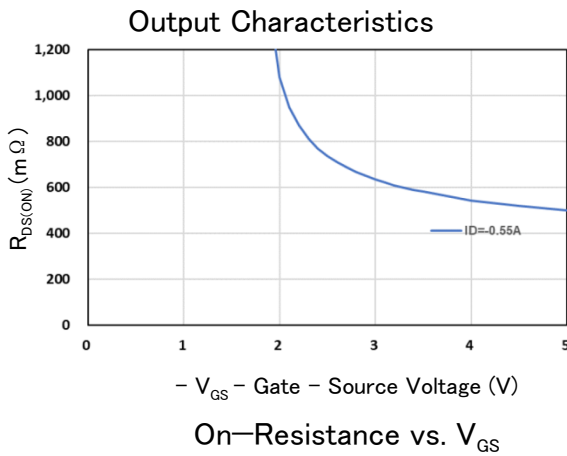
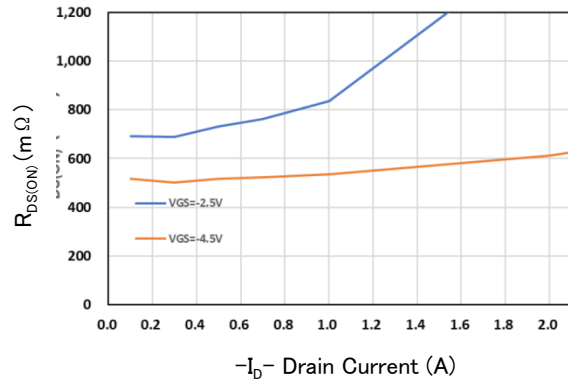
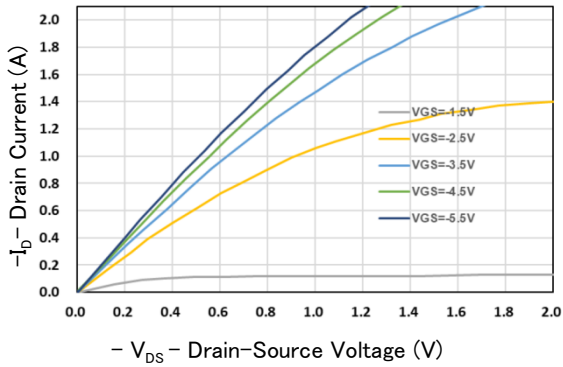
**Electrical Characteristics @25°C Unless Otherwise Noted**

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	-20			V
$V_{GS(th)}$	Gate-Threshold Voltage <sup>*2</sup>	$V_{DS}=V_{GS}, I_D=-250\mu A$	0.35	-0.45	-1.1	V
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS}=-20V, V_{GS}=0V$			-1.0	$\mu A$
$I_{GSS}$	Gate-Body Leakage Current	$V_{GS}=\pm 8V, V_{DS}=0V$			$\pm 10$	$\mu A$
$R_{DS(on)}$	Drain-Source On-Resistance <sup>*2</sup>	$V_{GS}=-4.5V, I_D=-0.55A$		530	640	$m\Omega$
		$V_{GS}=-2.5V, I_D=-0.45A$		730	950	$m\Omega$
		$V_{GS}=-1.8V, I_D=-0.35A$		1300	1950	$m\Omega$
$g_{FS}$	Forward Transconductance	$V_{DS}=-10V, I_D=-0.54A$		1.2		S
$V_{SD}$	Diode Forward Voltage	$I_S=-0.5A, V_{GS}=0V$			-1.2	V
<b>Dynamic Characteristics<sup>*4</sup></b>						
$C_{iss}$	Input Capacitance	$V_{DS}=-10V, V_{GS}=0V,$ $f=1MHz$		58		pF
$C_{oss}$	Output Capacitance			5.7		
$C_{rss}$	Reverse Transfer Capacitance			4.4		
<b>Switching Parameters<sup>*4</sup></b>						
$t_{d(on)}$	Turn-on Delay Time <sup>*3</sup>	$V_{GS}=-10V, V_{DD}=-4.5V,$ $I_D=-1.33A, R_{GEN}=3\Omega$		0.4		nS
$T_r$	Turn-on Rise Time <sup>*3</sup>			0.06		
$t_{d(off)}$	Turn-off Delay Time <sup>*3</sup>			0.02		
$T_f$	Turn-off Fall Time <sup>*3</sup>			0.8		

**Notes:**

- \*1. Surface mounted on FR4 board using the minimum recommended pad size.
- \*2. Pulse Test : Pulse Width=300 $\mu s$ , Duty Cycle=2%.
- \*3. Switching characteristics are independent of operating junction temperatures.
- \*4. Guaranteed by design, not subject to producing.

Typical Characteristics



**Ordering Information**

Device	Package	Shipping	Tape wide	Emboss pitch	Tape specification	Notes
LX3139FB	DFN1006-3L	Tape & Reel 10000pcs /7" Reel	8mm	4mm	Conductive	

**Package Dimensions**

Package outline : DFN1006-3L

SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	0.45	0.50	0.55
A1	0.00	0.025	0.05
b	0.45	0.50	0.55
b1	0.10	0.15	0.20
C	0.12	0.15	0.18
D	0.95	1.00	1.05
E	0.55	0.60	0.65
E1	0.15	0.20	0.25
e	0.65BSC		
L	0.20	0.25	0.30
L1	0.05 REF.		

Notice:

- Lead plating: Pb free solder
- Lead thickness includes solder plating
- Other Tolerance:  $\pm 0.05$
- Dimensions are exclusive of Burrs, Mold Flash and Tie Bar extrusions
- Unit: mm